## **General Description**

The MAX1840/MAX1841 subscriber identity module (SIM)/smart card level translators provide level shifting and electrostatic discharge (ESD) protection for SIM and smart card ports. These devices integrate two unidirectional level shifters for the reset and clock signals, a bidirectional level shifter for the serial data stream, and  $\pm 10$ kV ESD protection on all card contacts.

The MAX1840 includes a SHDN control input to aid insertion and removal of SIM and smart cards, while the MAX1841 includes a system-side data driver to support system controllers without open-drain outputs. The logic supply voltage range is +1.4V to +5.5V for the "controller side" and +1.7V to +5.5V for the "card side." Total supply current is 1.0µA. Both devices automatically shut down when either power supply is removed. For a complete SIM card interface, combine the MAX1840/MAX1841 with the MAX1686H 0V/3V/5V regulated charge pump.

The MAX1840/MAX1841 are available in ultra-small 10-pin  $\mu$ MAX packages that are only 1.09mm high and half the area of an 8-pin SO.

The MAX1840/MAX1841 are compliant with GSM test specifications 11.11 and 11.12.

### Applications

SIM Interface in GSM Cellular Telephones

Smart Card Readers

Logic Level Translation

SPI™/QSPI™/MICROWIRE™ Level Translation



### **Typical Operating Circuit**

# 

\_**Features** 

- SIM/Smart Card Level Shifting
- ♦ +1.4V to +5.5V Controller Voltage Range
- +1.7V to +5.5V Card Voltage Range
- ±10kV ESD Card Socket Protection
- ♦ Allows Level Translation with DV<sub>CC</sub> ≥ V<sub>CC</sub> or DV<sub>CC</sub> ≤ V<sub>CC</sub>
- Automatically Shuts Down When Either Supply Is Removed
- Card Contacts Actively Pulled Low During Shutdown
- 1µA Total Quiescent Supply Current
- ♦ 0.01µA Total Shutdown Supply Current
- Ultra-Small 10-Pin µMAX Package
- Compliant with GSM Test Specifications 11.11 and 11.12

### Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX1840EUB	-40°C to +85°C	10 µMAX
MAX1841EUB	-40°C to +85°C	10 µMAX

### Pin Configuration



SPI and QSPI are trademarks of Motorola, Inc. MICROWIRE is a trademark of National Semiconductor Corp.

Maxim Integrated Products 1

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### **ABSOLUTE MAXIMUM RATINGS**

 $\begin{array}{l} \mathsf{DV}_{CC}, \ \mathsf{V}_{CC} \ \text{to} \ \mathsf{GND}.....-0.3 \ \mathsf{V} \ \mathsf{to} \ \mathsf{+}6.0 \ \mathsf{V} \\ \mathsf{RIN}, \ \mathsf{CIN}, \ \mathsf{DATA}, \ \mathsf{DDRV}, \\ \hline \mathbf{SHDN} \ \mathsf{to} \ \mathsf{GND}....-0.3 \ \mathsf{V} \ \mathsf{to} \ (\mathsf{DV}_{CC} \ \mathsf{+} \ 0.3 \ \mathsf{V}) \\ \mathsf{RST}, \ \mathsf{CLK}, \ \mathsf{IO} \ \mathsf{to} \ \mathsf{GND}.....-0.3 \ \mathsf{V} \ \mathsf{to} \ (\mathsf{V}_{CC} \ \mathsf{+} \ 0.3 \ \mathsf{V}) \\ \mathsf{Continuous} \ \mathsf{Power} \ \mathsf{Dissipation} \ (\mathsf{T}_{\mathsf{A}} \ \mathsf{=} \ \mathsf{+}70^\circ \ \mathsf{C}) \\ \ \mathsf{10}\text{-}\mathsf{Pin} \ \mathsf{\mu}\mathsf{MAX} \ (\mathsf{derate} \ \mathsf{5.6mV}/^\circ \ \mathsf{C} \ \mathsf{above} \ \mathsf{+}70^\circ \ \mathsf{C}) \ \ldots...444 \ \mathsf{MW} \\ \end{array}$ 

Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

(Figure 1,  $DV_{CC} = +1.8V$ ;  $V_{CC} = +1.8V$ , +3.0V, or +5.0V;  $\overline{SHDN} = DV_{CC}$ , CIN = RIN = GND or  $DV_{CC}$ ,  $IO = V_{CC}$ ,  $DATA = DDRV = DV_{CC}$ ,  $C_{IO} = C_{CLK} = C_{RST} = C_{DATA} = 30$  pF, **T<sub>A</sub> = -40°C to +85°C**, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLIES					1	
DV <sub>CC</sub> Operating Range	DVCC		1.4		5.5	V
V <sub>CC</sub> Operating Range	V <sub>CC</sub>		1.7		5.5	V
DV <sub>CC</sub> Operating Current		CIN static		0.1	0.5	μΑ
	IDVCC	CIN clocked at 1.625MHz from GND to DV <sub>CC</sub> with 50% duty cycle		2.5		
		CIN clocked at 3.25MHz from GND to DV <sub>CC</sub> with 50% duty cycle		5		
		CIN static		0.9	3.0	μA
V <sub>CC</sub> Operating Current	IVCC	CIN clocked at 1.625MHz from GND to $\mbox{DV}_{\mbox{CC}}$ with 50% duty cycle		0.4		
		CIN clocked at 3.25MHz from GND to DV <sub>CC</sub> with 50% duty cycle		0.8		mA
Total Shutdown Current	ISHDN	$I_{OFF} = I_{VCC} + I_{DVCC}$ , $\overline{SHDN} = GND$ (MAX1840 only), or $DV_{CC} = GND$ or $V_{CC} = GND$		0.01	1	μA
CIN, RIN, SHDN, DDRV LOGIC	INPUTS		-			
Digital Input Low Threshold	VIL		$0.2 \times DV_{CO}$	2		V
Digital Input High Threshold	VIH			0	$.7 \times DV_{CC}$	V
Input Leakage Current				0.01	1	μA
CLK, RST OUTPUTS						
Digital Output Low Level	Vol	I <sub>SINK</sub> = 200μA			0.4	V
Digital Output High Level	V <sub>OH</sub>	$I_{SOURCE} = 20\mu A$	$0.9 \times V_{CC}$			- V
	VOH	I <sub>SOURCE</sub> = 200µA	0.8 × VCC			
DATA INPUT/OUTPUT						
DATA Pullup Resistance	Rdata	Between DATA and DV <sub>CC</sub>	13	20	28	kΩ
Input Low Threshold	VIL(DATA)	(Note 2)	0.3			V
Input High Threshold	VIH(DATA)	(Note 3)		D	V <sub>CC</sub> - 0.6	V
Input Low Current	Ι <sub>ΙL</sub>	$V_{CC} = 5.0V$			1	mA
Input High Current	IIH				2	μA



### **ELECTRICAL CHARACTERISTICS (continued)**

(Figure 1,  $DV_{CC} = +1.8V$ ;  $V_{CC} = +1.8V$ , +3.0V, or +5.0V;  $\overline{SHDN} = DV_{CC}$ , CIN = RIN = GND or  $DV_{CC}$ ,  $IO = V_{CC}$ ,  $DATA = DDRV = DV_{CC}$ ,  $C_{IO} = C_{CLK} = C_{RST} = C_{DATA} = 30$  pF, **T<sub>A</sub> = -40°C to +85°C**, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Output Low Level	VOL(DATA)	$IO = GND$ , $I_{SINK} = 100\mu A$			0.4	V	
		DV <sub>CC</sub> = 3.0V, IO = GND, I <sub>SINK</sub> = 200µA			0.4		
Output High Level	V <sub>OH</sub> (DATA)	I <sub>SOURCE</sub> = 10µA	$0.7 \times DV_{CO}$	)		V	
		$DV_{CC} = 3.0V$ , $I_{SOURCE} = 20\mu A$	$0.7 \times DV_{CC}$			v	
IO (INPUT/OUTPUT)	•						
IO Pullup Resistance	RIO	Between IO and V <sub>CC</sub>	6.5	10	14	kΩ	
Input Low Threshold	VIL(IO)	I <sub>IL(MAX)</sub> = 1mA (Note 2)	0.3			V	
Input High Threshold	VIH(IO)	$I_{IH(MAX)} = \pm 20\mu A \text{ (Note 3)}$			$0.7 \times V_{CC}$	V	
Input Low Current	Ι <sub>ΙL</sub>				1	mA	
Input High Current	Ιн				20	μA	
Output Low Level	V <sub>OL(IO)</sub>	DATA = GND or DDRV = GND, I <sub>SINK</sub> = 200μA			0.4	V	
Output High Level	VOH(IO)	Isource = 20µA	$0.8 \times V_{CC}$			V	
SHUTDOWN OUTPUT LEVELS							
Shutdown Output Levels (IO, CLK, RST)		$I_{SINK} = 200\mu A$ , $\overline{SHDN} = GND$ , DATA = CIN = RIN = DV <sub>CC</sub> (MAX1840 only)			0.4	V	
		$\begin{split} I_{SINK} &= 200 \mu \text{A}, \text{DV}_{CC} = \text{GND}, \overline{\text{SHDN}} \\ (\text{MAX1840}) &= \text{DDRV} (\text{MAX1841}) = \text{DATA} = \\ \text{CIN} &= \text{RIN} = \text{DV}_{CC} \end{split}$			0.4	V	
		$I_{SINK} = 200\mu$ A, $V_{CC} = GND$ , $\overline{SHDN}$ (MAX1840) = DDRV (MAX1841) = DATA = CIN = RIN = DV <sub>CC</sub>			0.4	V	
TIMING	·		·				
Maximum CLK Frequency	fclk	$V_{CC}$ = 2.7V to 5.5V, DV <sub>CC</sub> = 1.4V to 2.7V	5	20		MHz	
(Notes 4, 5)		$V_{CC} = 1.7V$ to 3.6V, $DV_{CC} = 1.4V$ to 2.25V	5	15			

Note 1: Specifications to -40°C are guaranteed by design, not production tested.

Note 2:  $V_{IL}$  is defined as the voltage at which the output (DATA/IO) voltage equals 0.5V.

Note 3:  $V_{IH}$  is defined as the voltage at which the output (DATA/IO) voltage exceeds the input (IO/DATA) voltage by 100mV.

Note 4: Timing specifications are guaranteed by design, not production tested.

Note 5: The maximum CLK frequency is defined as the output duty cycle remaining in the 40% to 60% range when the 50% CIN is applied. CIN has 5ns rise and fall times; levels are GND to DV<sub>CC</sub>. Input and output levels are measured at 50% of the waveform.

## **Typical Operating Characteristics**

(Circuit of Figure 1, DV<sub>CC</sub> = 3.0V, V<sub>CC</sub> = +5.0V, DDRV or DATA = DV<sub>CC</sub>, RIN = CIN = GND, T<sub>A</sub> = +25°C, unless otherwise noted.)



MAX1840/MAX1841

# **Typical Operating Characteristics (continued)**

(Circuit of Figure 1, DV<sub>CC</sub> = 3.0V, V<sub>CC</sub> = +5.0V, DDRV or DATA = DV<sub>CC</sub>, RIN = CIN = GND, T<sub>A</sub> = +25°C, unless otherwise noted.)



### Pin Description

MAX1840/MAX1841

PIN						
MAX1840	MAX1841	NAME	FUNCTION			
1	1	DATA	System Controller Data Input/Output. An open-drain IO with a $20k\Omega$ pull-up resistor to DV <sub>CC</sub> . For bidirectional data transfer, connect to an open-drain controller output capable of sinking 1mA while pulling DATA low. If the controller is not open-drain, use DDRV to send data and DATA to receive data.			
2	2	DVcc	Supply Voltage for System Controller Digital Pins. Set at +1.4V to +5.5V.			
3	3	CIN	System Controller Clock Input			
4	4	RIN	System Controller Reset Input			
	5	DDRV	Optional System Controller Data Input. Connect to controllers without an open-drain output. When not used, connect DDRV to $DV_{CC}$ .			
5		SHDN	Shutdown Mode Input. Driving SHDN low reduces the total supply current to less than 1µA. In shutdown mode, RST, CLK, and IO are actively pulled low and the transfer gate between DATA and IO is disabled. When not used, connect SHDN to DV <sub>CC</sub> .			
6	6	GND	System Controller and Card Ground			
7	7	RST	Reset Output to Card. Actively pulled low during shutdown.			
8	8	CLK	Clock Output to Card. Actively pulled low during shutdown.			
9	9	V <sub>CC</sub>	Supply Voltage for Card-Side Digital Pins. Set at +1.7V to +5.5V. Proper supply bypassing is required to meet ±10kV ESD specifications.			
10	10	IO	Card-Side Bidirectional Input/Output. An open-drain output with a 10k $\Omega$ pull-up resistor to V <sub>CC</sub> . For bidirectional data transfer, connect to an open-drain card output capable of sinking 1mA while pulling IO low. Actively pulled low during shutdown.			

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# **Detailed Description**

The MAX1840/MAX1841 provide the necessary level translation for interfacing with SIMs and smart cards in multivoltage systems. These devices operate with logic supply voltages between +1.4V and +5.5V on the controller side (DV<sub>CC</sub>) and between +1.7V and +5.5V on the card side (V<sub>CC</sub>). The total supply current (I<sub>DVCC</sub> + I<sub>VCC</sub>) is 1µA while operating in an idle state (see *Electrical Characteristics*). Figure 1 shows the MAX1840/MAX1841 test circuit. The *Typical Application Circuit* appears at the end of this data sheet.

#### Level Translation

The MAX1840/MAX1841 provide level translators for a clock input, a reset input, and a bidirectional data IO. The clock and reset inputs (CIN and RIN) are level shifted from the controller-side supply rails (DV<sub>CC</sub> to GND) to the card-side supply rails (V<sub>CC</sub> to GND). When connected to an open-drain controller output, DATA and IO provide bidirectional level translation. All level translation is valid for DV<sub>CC</sub>  $\geq$  V<sub>CC</sub> or DV<sub>CC</sub>  $\leq$  V<sub>CC</sub>. The MAX1840/MAX1841 contain internal pull up resistors from DATA to the controller-side supply (V<sub>CC</sub>). For push-pull controller outputs, see the *Data Driver* section for bidirectional data translation.

### Data Driver (MAX1841 Only)

When using a microcontroller ( $\mu$ C) without an open-drain output, use the data driver (DDRV) input to send data to the SIM/smart card, while DATA provides the controllerside output for bidirectional data transfer. When not used, connect DDRV to DV<sub>CC</sub> to reduce total supply current.

### **Shutdown Mode**

For the MAX1840, drive SHDN low to activate shutdown. Connect SHDN to DV<sub>CC</sub> or drive high for normal operation. To allow for card insertion and removal, shutdown mode actively pulls CLK, RST, and IO low; it also disconnects the internal 10k $\Omega$  pull up resistor from V<sub>CC</sub> to prevent excessive current draw. Shutdown mode reduces the total supply current (I<sub>DVCC</sub> + I<sub>VCC</sub>) to 0.01µA.

### SIM/Smart Card Insertion/Removal

The SIM/smart card specifications require that the cardside pins (V<sub>CC</sub>, CLK, RST, IO) be at ground potential prior to inserting the SIM/smart card. For applications using the MAX1686H (Figure 3), the easiest way to achieve this is by shutting down the MAX1686H or by



Figure 1. MAX1840/MAX1841 Test Circuit

driving SHDN (MAX1840 only) low. If specific sequencing is desired, pull IO low by driving either DATA or DDRV (MAX1841 only) low, and pull CLK and RST low by driving CIN and RIN low, respectively.

#### **ESD** Protection

As with all Maxim devices, ESD-protection structures on all pins protect against ESDs encountered during handling and assembly. For further protection during card insertion and removal, the pins that connect to the card socket (CLK, RST, IO, V<sub>CC</sub>, and GND) provide protection against  $\pm$ 10kV of ESD. The ESD structures withstand high ESD in all states: normal operation, shutdown, and power-down. After an ESD event, the MAX1840/MAX1841 continue working without latchup. A 1µF bypass capacitor from V<sub>CC</sub> to GND is required to exceed  $\pm$ 10kV ESD specifications.

### **ESD** Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report documenting test setup, test methodology, and test results.

### **Applications Information**

### SIM/Smart Card Interface

To provide 5V when interfacing with a 5V SIM/smart card, +3V systems require a DC-DC converter. The MAX1686H +5V regulating charge pump for SIM cards provides



Figure 2. Using MAX1840/MAX1841 and MAX1686/MAX1686H Charge Pump for SIM Card Applications

0V/3V/5V for full compatibility with SIM/smart-card specifications. Figure 2 shows the charge pump for SIM card applications. Alternatively, the MAX619 generates a regulated 5V from input voltages as low as 2V.

### **SPI/QSPI/MICROWIRE Interface**

The MAX1840/MAX1841 are also useful as 3V/5V level shifters in SPI, QSPI, and MICROWIRE applications (Figure <u>3</u>). On the slave side, connect CLK to SCLK, RST to CS, and IO to DOUT and DIN. The unidirectional



Figure 3. MAX1840/MAX1841 with SPI/QSPI/MICROWIRE Interfaces

level shifters transfer chip select and clock signals to the slave device(s), while the bidirectional level shifter transfers data.

### **Chip Information**

TRANSISTOR COUNT: 211







Note: The MAX1840/MAX1841 do not have an exposed pad.

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